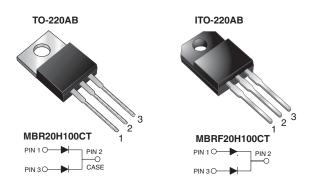


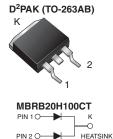
## MBR20H100CT, MBRF20H100CT, MBRB20H100CT

Wishay General Semiconductor

## **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance





### **DESIGN SUPPORT TOOLS**

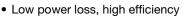
click logo to get started



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>RRM</sub>	100 V				
I <sub>FSM</sub>	250 A				
I <sub>R</sub>	4.5 μA				
V <sub>F</sub>	0.64 V				
T <sub>J</sub> max.	175 °C				
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configurations	Common cathode				

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection



- Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H100CT	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	100			
Working peak reverse voltage		$V_{RWM}$	100	V		
Maximum DC blocking voltage		$V_{DC}$	100			
Maximum average forward rectified current	total device	le(A\A	20	Α		
Maximum average forward rectified current	per diode		10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	250	A		
Peak repetitive reverse current per diode at t <sub>p</sub> = 2.0 µs, 1 kHz		I <sub>RRM</sub>	1.0			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T <sub>J</sub> . T <sub>STG</sub>	-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500	V		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> (1)	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	0.77	- V	
		I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.64		
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C	0.88		
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I <sub>R</sub> <sup>(2)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	4.5	μΑ	
			T <sub>J</sub> = 125 °C	6.0	mA	

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

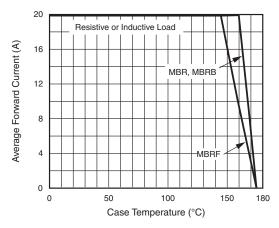
(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	5.8	2.0	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H100CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF20H100CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB20H100CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB20H100CT-E3/81	1.35	81	800/reel	Tape and reel	

# MBR20H100CT, MBRF20H100CT, MBRB20H100CT

## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)



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Fig. 1 - Forward Current Derating Curve

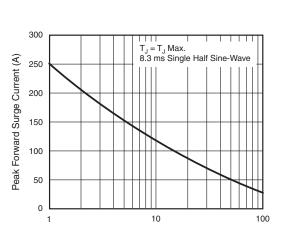


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

Number of Cycles at 60 Hz

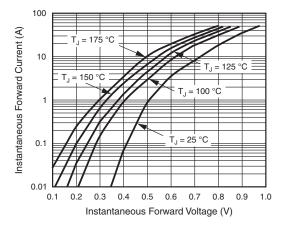


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

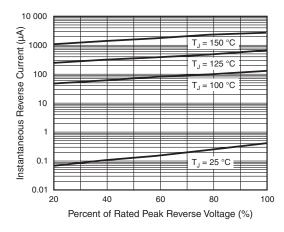


Fig. 4 - Typical Reverse Characteristics Per Diode

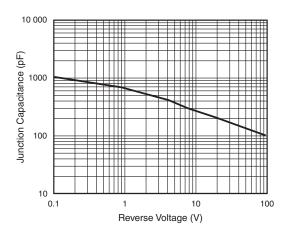


Fig. 5 - Typical Junction Capacitance Per Diode

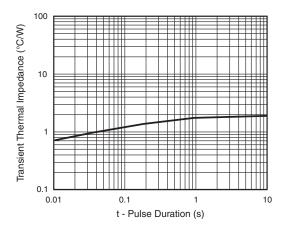


Fig. 6 - Typical Transient Thermal Impedance Per Diode

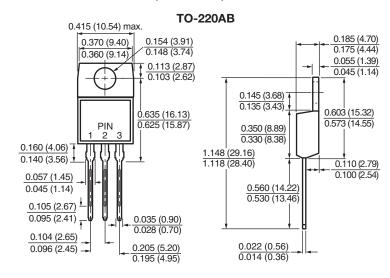


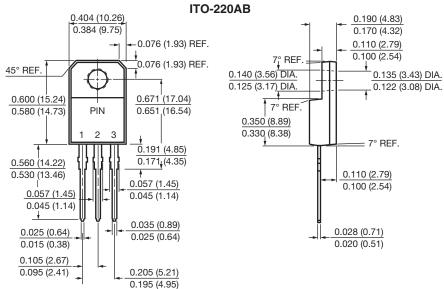


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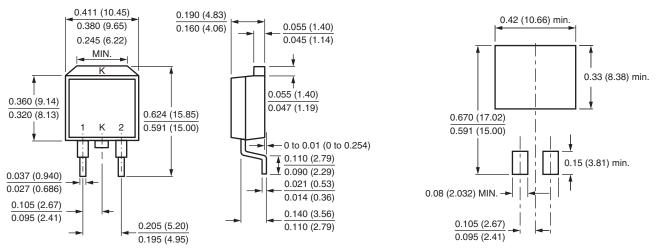
### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





#### D<sup>2</sup>PAK (TO-263AB)

### **Mounting Pad Layout**





## **Legal Disclaimer Notice**

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